

PHOTOCOUPLER

PS2533-1,PS2533L-1

HIGH COLLECTOR TO EMITTER VOLTATGE HIGH ISOLATION VOLTAGE MULTI PHOTOCOUPLER SIRIES

-NEPOC Series-

DESCRIPTION

The PS2533-1 and PS2533L-1 are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon darlington connected phototransistor.

The PS2533-1 is in a plastic DIP (Dual In-line Package) and the PS2533L-1 is lead bending type (Gull-wing) for surface mount.

FEATURES

- High collector to emitter voltage (VcEo = 350 V)
- High Isolation voltage (BV = 5 000 Vr.m.s.)
- High current transfer ratio (CTR = 4 000% TYP.)

• Ordering number of tape product: PS2533L-1-F3: 2 000 pcs/reel

- High-speed switching (tr, tf = 100 μ s TYP.)
- · Safety standards

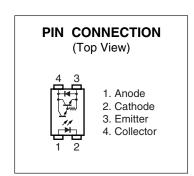
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- UL approved: No. E72422
- CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
- BSI approved: No. 8221/8222
- SEMKO approved: No. 903238
- NEMKO approved: No. P09210868
- DEMKO approved: No. 314999
- FIMKO approved: No. FI 25119
- DIN EN60747-5-2 (VDE0884 Part2) approved: No. 40008862 (Option)

APPLICATIONS

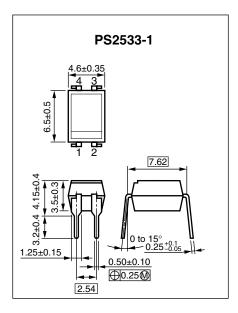
- · Telephone, Exchange equipment
- FAX/MODEM



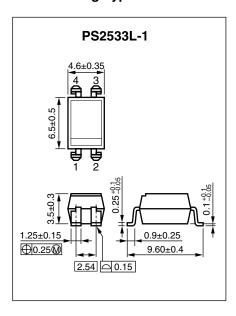
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<R> PACKAGE DIMENSIONS (Unit: mm)

DIP Type



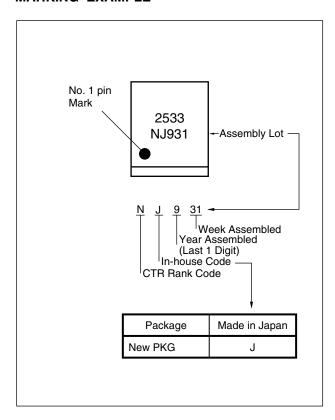
Lead Bending Type



<R> PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	7 mm
Outer Creepage Distance	7 mm
Inner Creepage Distance	4 mm
Isolation Thickness	0.4 mm

<R> MARKING EXAMPLE



<R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number ¹
PS2533-1	PS2533-1-A	Pb-Free	Magazine case 100 pcs	Standard products	PS2533-1
PS2533L-1	PS2533L-1-A			(UL, CSA, BSI,	
PS2533L-1-F3	PS2533L-1-F3-A		Embossed Tape 2 000 pcs/reel	SEMKO, NEMKO,	
				DEMKO, FIMKO	
				approved)	
PS2533-1-V	PS2533-1-V-A		Magazine case 100 pcs	DIN EN60747-5-2	
PS2533L-1-V	PS2533L-1-V-A			(VDE0884 Part2)	
PS2533L-1-V-F3	PS2533L-1-V-F3-A		Embossed Tape 2 000 pcs/reel	Approved (Option)	

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	80	mA
	Reverse Voltage	VR	6	٧
	Power Dissipation Derating	⊿P₀/°C	1.5	mW°C
	Power Dissipation	PD	150	mW
	Peak Forward Current 1	IFP	1	Α
Transistor	Collector to Emitter Voltage	VCEO	350	٧
	Emitter to Collector Voltage	VECO	0.6	٧
	Collector Current	lc	150	mA
	Power Dissipation Derating	⊿Pc/°C	3.0	mW/°C
	Power Dissipation	Pc	300	mW
Isolation Voltage ²		BV	5 000	Vr.m.s.
Operating A	Operating Ambient Temperature		-55 to +100	°C
Storage Temperature		Tstg	-55 to +150	°C

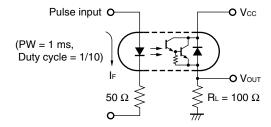
^{*1} PW = 100 μ s, Duty Cycle = 1%

^{*2} AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.

ELECTRICAL CHARACTERISTICS (TA = 25°C)

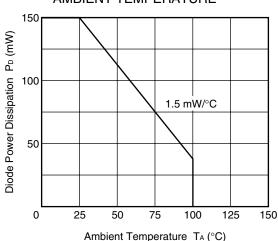
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.15	1.40	V
	Reverse Current	lR	V _R = 5 V			5	μΑ
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		30		pF
Transistor	Collector to Emitter Dark Current	Iceo	VcE = 350 V, I _F = 0 mA			400	nA
Coupled	Current Transfer Ratio (Ic/IF)	CTR	I _F = 1 mA, V _{CE} = 2 V	1 500	4 000	6 500	%
	Collector Saturation Voltage	VCE (sat)	I _F = 1 mA, I _C = 2 mA			1.0	V
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVpc	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.6		pF
	Rise Time ^{*1}	tr	Vcc = 5 V, Ic = 10 mA, RL = 100 Ω		100		μs
	Fall Time ^{*1}	t _f			100		

*1 Test circuit for switching time



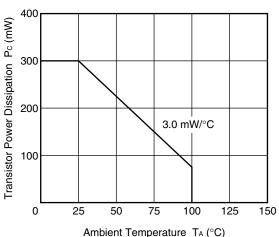
TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)



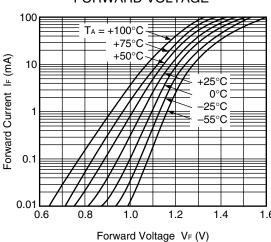


vs. AMBIENT TEMPERATURE

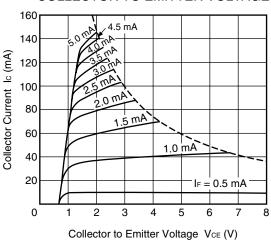
TRANSISTOR POWER DISSIPATION



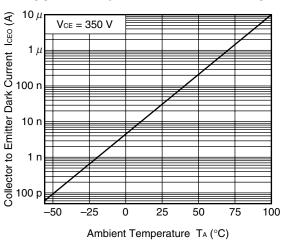
FORWARD CURRENT vs. FORWARD VOLTAGE



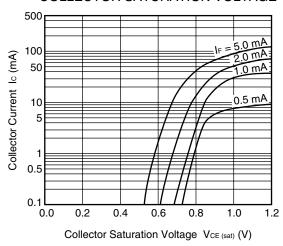
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



COLLECTOR TO EMITTER DARK **CURRENT vs. AMBIENT TEMPERATURE**

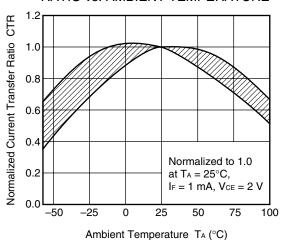


COLLECTOR CURRENT vs. **COLLECTOR SATURATION VOLTAGE**

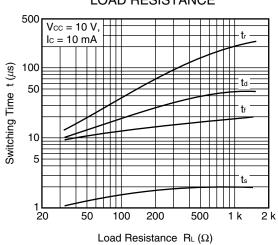


Remark The graphs indicate nominal characteristics.

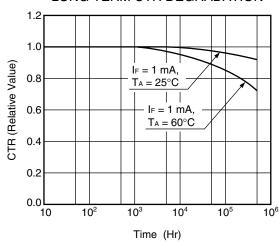
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



SWITCHING TIME vs. LOAD RESISTANCE

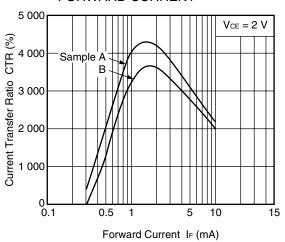


LONG TERM CTR DEGRADATION

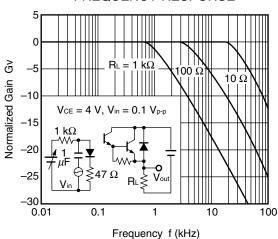


Remark The graphs indicate nominal characteristics.

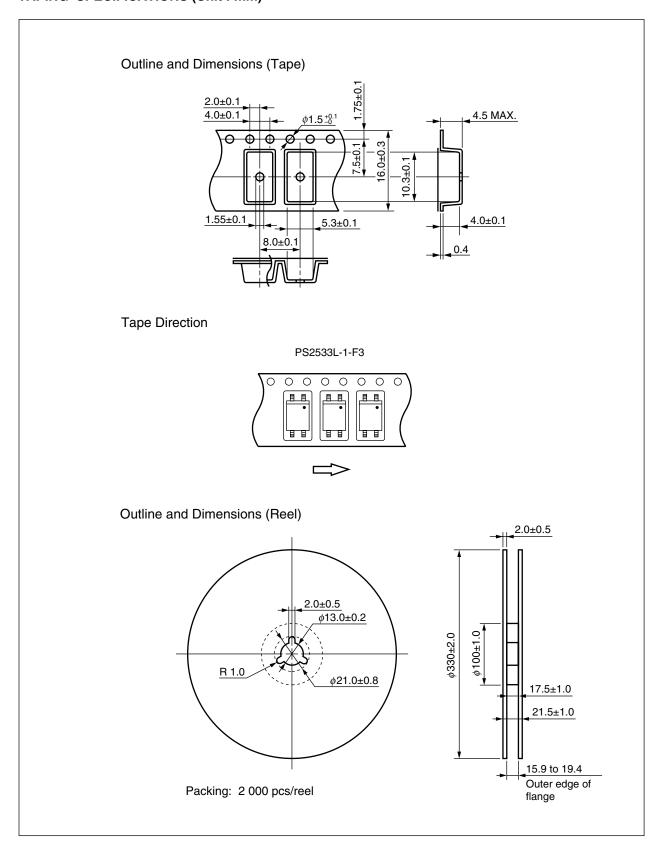
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



FREQUENCY RESPONSE



<R> TAPING SPECIFICATIONS (Unit: mm)



NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

• Peak reflow temperature 260°C or below (package surface temperature)

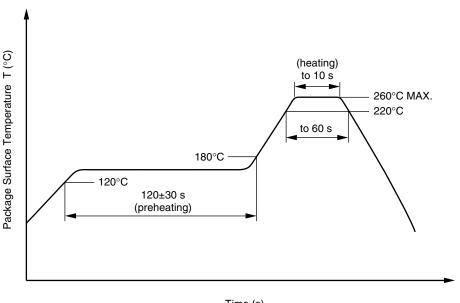
• Time of peak reflow temperature 10 seconds or less • Time of temperature higher than 220°C 60 seconds or less

• Time to preheat temperature from 120 to 180°C 120±30 s Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

 Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

· Preheating conditions 120°C or below (package surface temperature)

· Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Soldering by soldering iron

• Peak temperature (lead part temperature) 350°C or below • Time (each pins) 3 seconds or less

Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead.
- (b) Please be sure that the temperature of the package would not be heated over 100°C.

(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.

<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT (VDE0884)

Parameter	Symbol	Speck	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.5 \times U_{\text{IORM}}, P_{\text{d}} < 5 \text{pC}$	Ulorim Upr	890 1 335	V _{peak} V _{peak}
Test voltage (partial discharge test, procedure b for all devices test) $U_{pr}=1.875\times U_{IORM},P_d<5pC$	U_pr	1 669	V_{peak}
Highest permissible overvoltage	Utr	8 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
Storage temperature range	T _{stg}	-55 to +150	°C
Operating temperature range	Та	-55 to +100	°C
Isolation resistance, minimum value VIO = 500 V dc at TA = 25°C VIO = 500 V dc at TA MAX. at least 100°C	Ris MIN. Ris MIN.	10 ¹² 10 ¹¹	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current IF, Psi = 0) Power (output or total power dissipation) Isolation resistance	Tsi Isi Psi	175 400 700	°C mA mW
V _{IO} = 500 V dc at T _A = 175°C (Tsi)	Ris MIN.	10°	Ω

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
- Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

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